ON Semiconductor

Is Now

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NTD6N40

Preferred Device

Power MOSFET 6 Amps, 400 Volts **N-Channel DPAK**

Designed for high voltage, high speed switching applications in power supplies, converters, power motor controls and bridge circuits.

Features

- Higher Current Rating
- Lower R_{DS(on)}
- Lower Capacitances
- Lower Total Gate Charge
- Tighter V_{SD} Specifications
- Avalanche Energy Specified
- Industry Standard DPAK Surface Mount Package

Typical Applications

- Switch Mode Power Supplies
- PWM Motor Controls
- Converters
- Bridge Circuits

MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

Symbol	Value	Unit
V _{DSS}	400	Vdc
V _{DGR}	400	Vdc
V _{GS} V _{GSM}	±20 ±40	Vdc
I _D I _D I _{DM}	6.0 4.2 21	Adc
PD	96 0.77 1.75	Watts W/°C W/°C
T _J , T _{stg}	– 55 to 150	°C
E _{AS}	180	mJ
R _{θJC} R _{θJA} R _{θJA}	1.30 100 71.4	°C/W
ΤL	260	°C
	VDSS VDGR VGS VGSM ID ID ID PD TJ, Tstg EAS ReJC ReJA ReJA ReJA	VDSS 400 VDGR 400 VGS ±20 VGSM ±40 ID 6.0 ID 4.2 IDM 21 PD 96 0.77 1.75 TJ, Tstg -55 to T50 EAS ReJC 1.30 ReJA 100 ReJA 71.4

 When surface mounted to an FR4 board using the minimum recommended pad size.



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http://onsemi.com

6 AMPERES

400 VOLTS R_{DS(on)} = 1.1 Ω

N-Channel



MARKING

= Year = Work Week

WW

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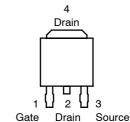
= MOSFET

CASE 369A

DPAK

STYLE 2





ORDERING INFORMATION

Device	Package	Shipping
NTD6N40	DPAK	75 Units/Rail
NTD6N40-1	DPAK	75 Units/Rail
NTD6N40T4	DPAK	2500 Tape & Reel

Preferred devices are recommended choices for future use and best overall value.

NTD6N40

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Drain-to-Source Breakdown Voltage (V _{GS} = 0 Vdc, I _D = 0.25 mAdc) Temperature Coefficient (Positive)	V _{(BR)DSS}	400 -	_ 500		Vdc mV/°C
Zero Gate Voltage Collector Current ($V_{DS} = 400 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}$) ($V_{DS} = 400 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}, T_J = 125^{\circ}\text{C}$)	I _{DSS}			10 100	μAdc
Gate-Body Leakage Current (V_{GS} = ±20 Vdc, V_{DS} = 0)	I _{GSS(f)} I _{GSS(r)}			100 100	nAdc

ON CHARACTERISTICS (Note 1)

Gate Threshold Voltage $I_D = 0.25 \text{ mA}, V_{DS} = V_{GS}$ Temperature Coefficient (Negative)	V _{GS(th)}	2.0	2.7 6.0	4.0	Vdc mV/°C
Static Drain-to-Source On-Resistance (V _{GS} = 10 Vdc, I _D = 3 Adc)	R _{DS(on)}	-	900	1100	mOhm
$\label{eq:constraint} \begin{array}{l} \mbox{Drain-to-Source On-Voltage} \\ (V_{GS} = 10 \mbox{ Vdc}, \mbox{ I}_{D} = 6 \mbox{ Adc}) \\ (V_{GS} = 10 \mbox{ Vdc}, \mbox{ I}_{D} = 3 \mbox{ Adc}, \mbox{ T}_{J} = 125^{\circ}\mbox{C}) \end{array}$	V _{DS(on)}		- 6	7.9 6.9	Vdc
Forward Transconductance (V _{DS} = 15 Vdc, I _D = 3 Adc)	9 _{FS}	2.0	4.4	-	mhos
DYNAMIC CHARACTERISTICS					

DYNAMIC CHARACTERISTICS

Input Capacitance		C _{iss}	-0	515	720	pF
Output Capacitance	(V _{DS} = 25 Vdc, V _{GS} = 0 Vdc, f = 1.0 MHz)	C _{oss}		185	260	
Transfer Capacitance		C _{rss}		15	30	
SWITCHING CHARACTERISTIC	S (Note 2)	5.5	<u> </u>			

SWITCHING CHARACTERISTICS (Note 2)

Turn-On Delay Time	5	t _{d(on)}	-	7.0	10	ns
Rise Time	$(V_{DD}=200 \; Vdc, \; I_{D}=6 \; Adc, \\ V_{GS}=10 \; Vdc, \\ R_{G}=9.1 \; \Omega)$	tr	-	11	20	
Turn-Off Delay Time	$R_{\rm G} = 9.1 \ \Omega$	t _{d(off)}	-	19	40	
Fall Time	N. 10-	t _f	-	10	20	
Gate Charge		QT	-	9.5	19	nC
	(V _{DS} = 320 Vdc, I _D = 6 Adc, V _{GS} = 10 Vdc)	Q ₁	-	2.0	-	
	V _{GS} = 10 Vdc)	Q ₂	-	3.0	-	
		Q ₃	-	6.0	-	

SOURCE-DRAIN DIODE CHARACTERISTICS

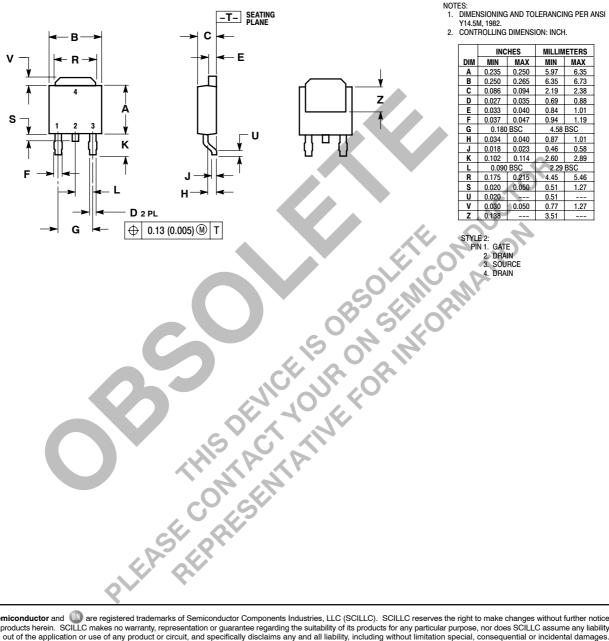
Forward On-Voltage (Note 1)		V _{SD}				Vdc
	$(I_S = 6 \text{ Adc}, V_{GS} = 0 \text{ Vdc})$ $(I_S = 6 \text{ Adc}, V_{GS} = 0 \text{ Vdc}, T_J = 125^{\circ}\text{C})$		-	0.9	1.0	
	$(I_S = 6 \text{ Adc}, V_{GS} = 0 \text{ Vdc}, T_J = 125^{\circ}\text{C})$		-	0.8	-	
Reverse Recovery Time		t _{rr}	-	270	-	ns
Q *		t _a	-	110	-	
	(I _S = 6 Adc, V _{GS} = 0 Vdc, di _S /dt = 100 A/μs)	t _b	-	160	-	
Reverse Recovery Stored Charge		Q _{RR}	-	1.6	_	μC

Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.
Switching characteristics are independent of operating junction temperature.

NTD6N40

PACKAGE DIMENSIONS





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